NSN 5961-01-082-1989

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
End Application:
9arleigh burke class ddg; forrestal class cv; landing craft air cushion (lcac); kidd class ddg; spruance class dd (963); engine, aircraft
tf33-pw-102 (c-135e, ec-135h/k/p); nimitz class cvn; ticonderoga class cg (47); support equipment, b-52 aircraft
Mounting Method:
Press fit
Features Provided:
Hermetically sealed case
Criticality Code Justification:
Feat
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
110.0 reverse voltage, peak
Special Features:
Weapon system essential; junction pattern arrangement: pin
Terminal Type And Quantity:
1 pin
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
No
Fiig:
A110a0